

Supporting Information for

CuO/ZnO Heterojunction Nanorod Arrays Prepared by Photochemical Method with Improved UV Detecting Performance

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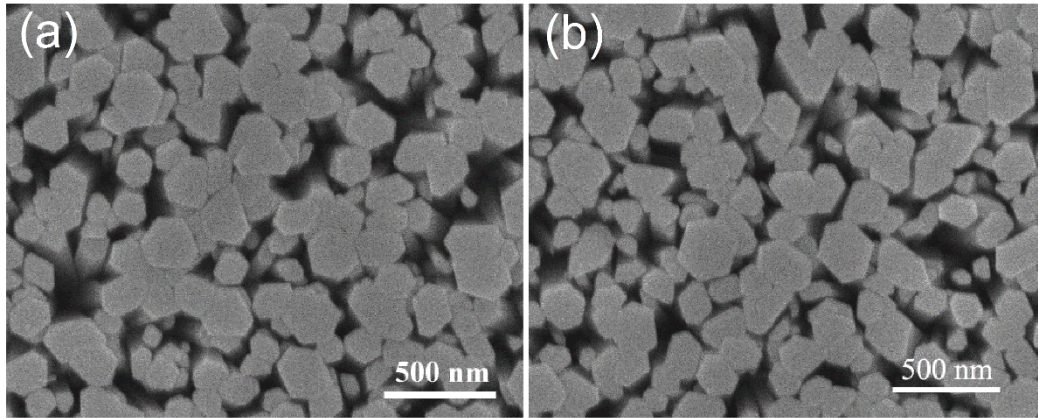


Figure S1. the surface image of (a) the as-grown ZnO nanorod arrays (NRs) and (b) the 400 °C annealing ZnO NRs. Annealing at 400 °C has no effect on the surface morphology of ZnO NRs.

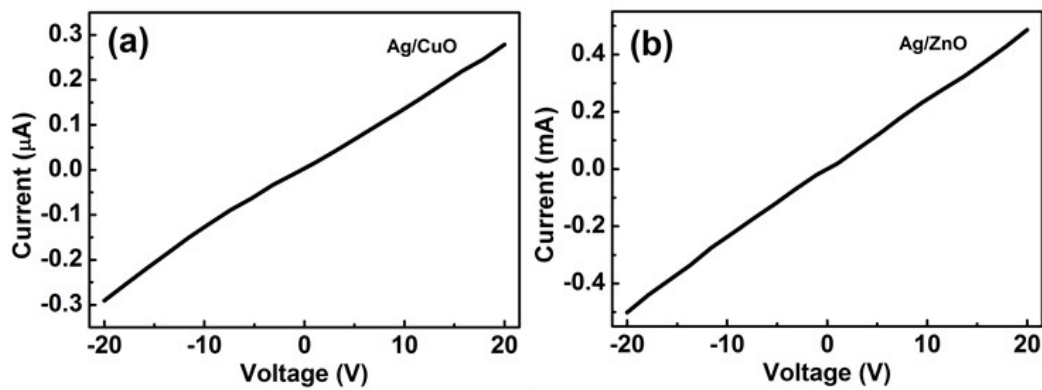


Figure S2. The V-I curves of (a) Ag-CuO and (b) AZO-ZnO. Both V-I curves shows a good ohmic contact.